

R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/tank and Cauer/filter configurations are included. When implemented in P-SPICE, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in application note AN609, "Thermal Simulation of Power MOSFETs on the P-SPICE Platform".

R-C THERMAL MODEL FOR TANK CONFIGURATION

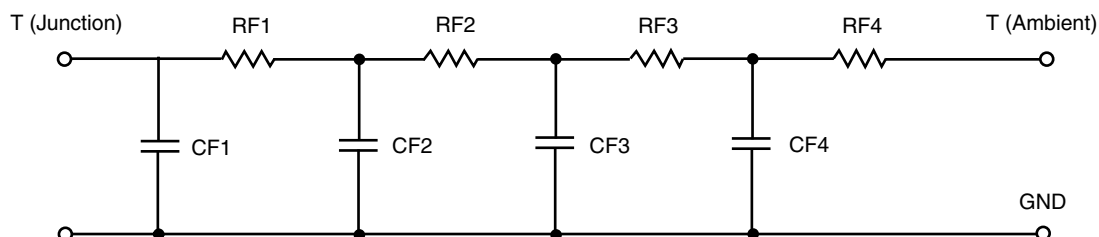


R-C VALUES FOR TANK CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RT1	13.8336	772.2000 m	N/A
RT2	13.0221	1.1867	N/A
RT3	11.9864	1.4744	N/A
RT4	55.1579	1.9667	N/A
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	10.7044 m	272.2830 u	N/A
CT2	108.6719 m	5.2253 m	N/A
CT3	659.5846 u	3.1851 m	N/A
CT4	1.5240	1.2049 m	N/A

Note

N/A indicates not applicable

This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.

R-C THERMAL MODEL FOR FILTER CONFIGURATION**R-C VALUES FOR FILTER CONFIGURATION**

THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RF1	8.8028	957.1000 m	N/A
RF2	17.1534	1.6848	N/A
RF3	14.3596	1.4522	N/A
RF4	53.6842	1.3059	N/A
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CF1	383.2541 u	175.6001 u	N/A
CF2	4.3011 m	349.2834 u	N/A
CF3	81.5798 m	729.6148 u	N/A
CF4	1.4555	231.7503 u	N/A

Note

N/A indicates not applicable

